



DMM I 390

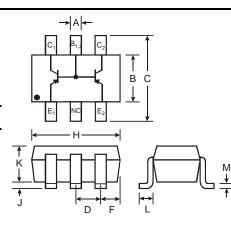
MATCHED PNP SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- **Epitaxial Planar Die Construction** .
- Intrinsically Matched PNP Pair (Note 1)
- Small Surface Mount Package
- 2% hFE Matched Tolerance
- Lead Free/RoHS Compliant (Note 3)
- "Green" Device (Note 4 and 5)

Mechanical Data

- Case: SOT-26
- Case Material: Molded Plastic, "Green" Molding • Compound, Note 5. UL Flammability Classification Rating 94V-0
- Terminal Connections: See Diagram .
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over
- Copper leadframe).
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.015 grams (approximate)



SOT-26								
Dim	Min	Max	Тур					
Α	0.35	0.50	0.38					
В	1.50	1.70	1.60					
С	2.70	3.00	2.80					
D	_		0.95					
F	_		0.55					
Н	2.90	3.10	3.00					
J	0.013	0.10	0.05					
Κ	1.00	1.30	1.10					
L	0.35	0.55	0.40					
М	0.10	0.20	0.15					
All Dimensions in mm								

Maximum Ratings $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	Value	Unit	
Collector-Base Voltage	V _{CBO}	-40	V	
Collector-Emitter Voltage	V _{CEO}	-40	V	
Emitter-Base Voltage	V _{EBO}	-5.0	V	
Collector Current - Continuous	IC	-200	mA	
Power Dissipation (Note 2)	Pd	225	mW	
Thermal Resistance, Junction to Ambient (Note 2)	R _{θJA}	556	°C/W	
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +150	°C	

Notes: 1

Built with adjacent die from a single wafer. Device mounted on FR5 PCB: 1.0 x 0.75 x 0.62 in.; pad layout as shown on suggested pad layout document AP02001, which can be found on our 2. website at http://www.diodes.com/datasheets/ap02001.pdf.

3. No purposefully added lead.

Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php. 4.

5. Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

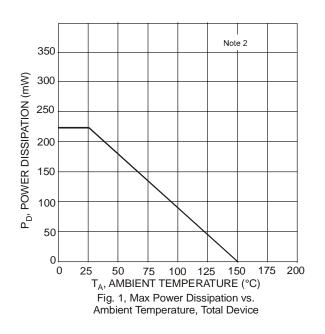


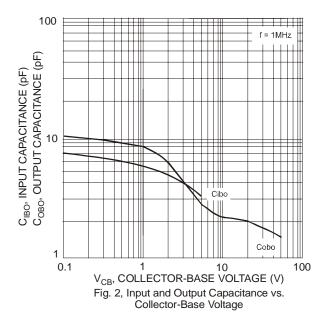
Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition			
OFF CHARACTERISTICS (Note 6)	Symbol	IVIIII	IVIdX	Unit	Test Condition			
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-40	_	V	$I_{C} = -10\mu A, I_{E} = 0$			
Collector-Emitter Breakdown Voltage	V(BR)CEO	-40		v	$I_{\rm C} = -1.0 {\rm mA}, I_{\rm B} = 0$			
Emitter-Base Breakdown Voltage	V(BR)EBO	-5.0		v	$I_E = -10\mu A$, $I_C = 0$			
Collector Cutoff Current	I _{CEX}		-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -3.0V$			
Base Cutoff Current	IBL		-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -3.0V$			
ON CHARACTERISTICS (Note 6)	'BL		00	10.0	VCE = 0.000, VEB(OFF) = 0.000			
DC Current Gain (Note 7)	h _{FE}	60 80 100 60 30	 300 	_	$\begin{split} I_{C} &= -100\mu A, \ V_{CE} &= -1.0V \\ I_{C} &= -1.0mA, \ V_{CE} &= -1.0V \\ I_{C} &= -10mA, \ V_{CE} &= -1.0V \\ I_{C} &= -50mA, \ V_{CE} &= -1.0V \\ I_{C} &= -100mA, \ V_{CE} &= -1.0V \end{split}$			
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		-0.25 -0.40	V	$I_{C} = -10$ mA, $I_{B} = -1.0$ mA $I_{C} = -50$ mA, $I_{B} = -5.0$ mA			
Base-Emitter Saturation Voltage	V _{BE(SAT)}	V _{BE(SAT)} -0.65		V	$I_{C} = -10mA$, $I_{B} = -1.0mA$ $I_{C} = -50mA$, $I_{B} = -5.0mA$			
SMALL SIGNAL CHARACTERISTICS								
Output Capacitance	C _{obo}		4.5	pF	$V_{CB} = -5.0V$, f = 1.0MHz, I _E = 0			
Input Capacitance	C _{ibo}		10	pF	$V_{EB} = -0.5V, f = 1.0MHz, I_{C} = 0$			
Input Impedance	h _{ie}	2.0	12	kΩ				
Voltage Feedback Ratio	h _{re}	0.1	10	x 10 ⁻⁴	$V_{CE} = 10V, I_C = 1.0mA,$			
Small Signal Current Gain	h _{fe}	100	400	—	f = 1.0 kHz			
Output Admittance	h _{oe}	3.0	60	μS				
Current Gain-Bandwidth Product	f⊤	250		MHz	$V_{CE} = -20V, I_{C} = -10mA, f = 100MHz$			
Noise Figure	NF		4.0	dB	V_{CE} = -5.0V, I _C = -100µA, R _S = 1.0kΩ, f = 1.0kHz			
SWITCHING CHARACTERISTICS								
Delay Time	t _d		35	ns	$V_{\rm CC} = -3.0V, I_{\rm C} = -10mA,$			
Rise Time	tr	_	35	ns	$V_{BE(off)} = 0.5V, I_{B1} = -1.0mA$			
Storage Time	ts		225	ns	$V_{CC} = -3.0V, I_{C} = -10mA,$			
Fall Time			75	ns	$I_{B1} = I_{B2} = -1.0 \text{mA}$			

6. Short duration pulse test used to minimize self-heating effect.

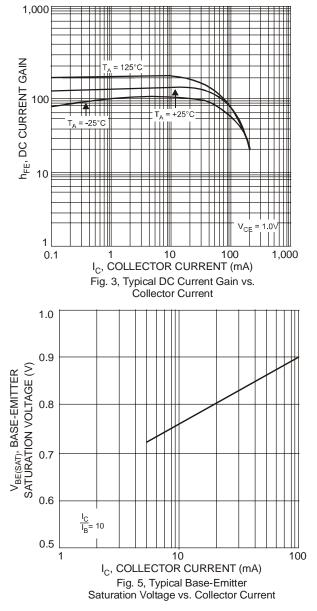
7. The DC current gain, h_{FE}, is matched at I_C = -10mA and V_{CE} = -1.0V with typical matched tolerances of 1% and maximum of 2%.

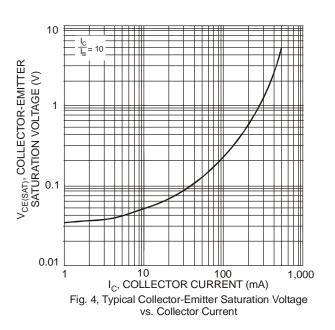




Notes:







Ordering Information (Note 5 & 8)

Device	Packaging	Shipping			
DMMT3906-7-F	SOT-26	3000/Tape & Reel			

Notes: 8. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information

	nation											
K3Q K3Q K3Q YM = Date Code Marking Code YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September												
Year	2004	20	05	2006	2007	20	08	2009	2010	20	11	2012
Code	R		S	Т	U	Ņ	/	W	Х	Ň	Y	Z
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



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